



Digital Systems and Computer Architecture

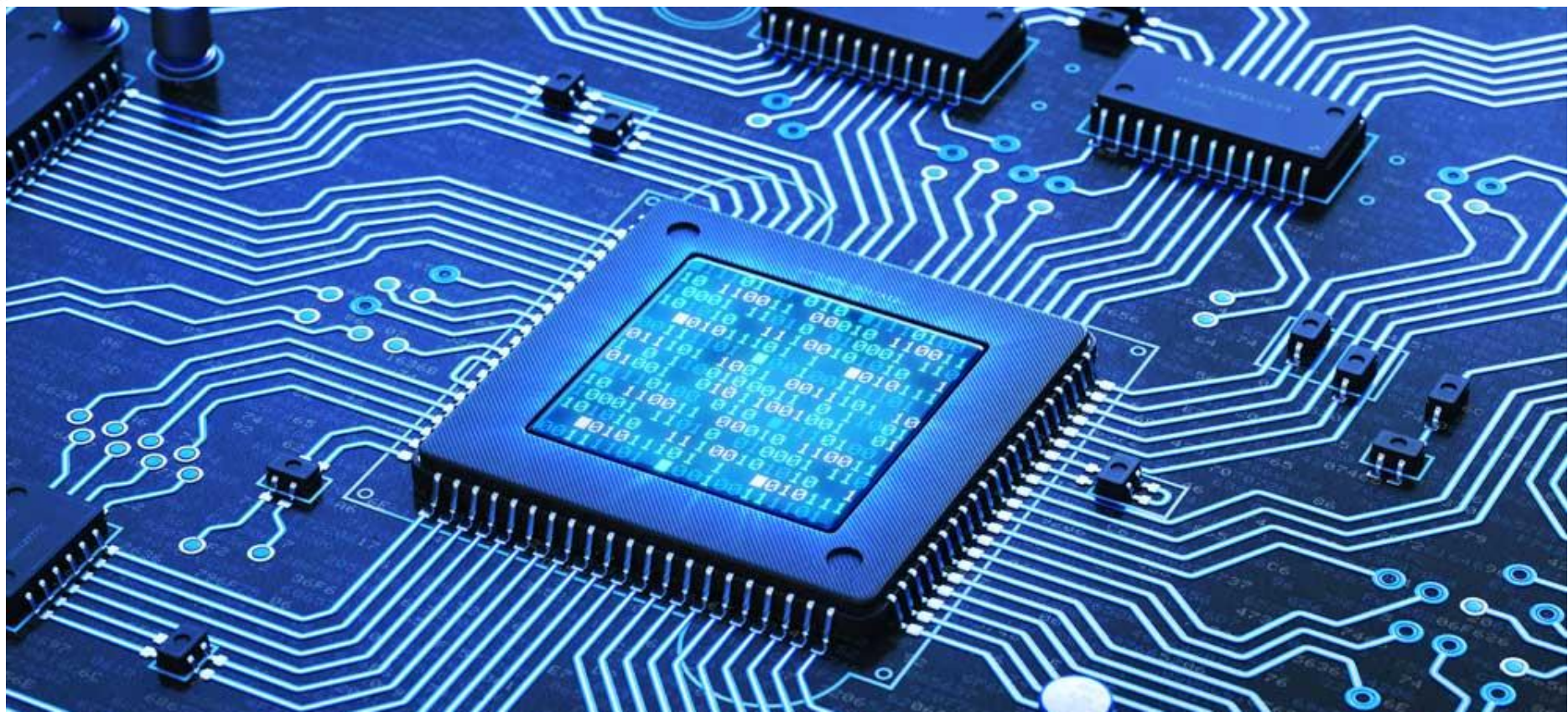
Session 1.6

Module 1b

Semiconductors, p-type and n-type Materials

Session 1.6: Focus

- Conductors, insulators and semiconductors
 - Atomic structure
 - Conductivity of copper
 - Conduction and valence bands
 - Resistivity (ρ)
- Intrinsic or pure semiconductors
 - Doping materials
 - Trivalent elements
 - Pentavalent elements
- Doped semiconductors
 - p-type and n-type
 - Types of doping



Conductors, Insulators and Semiconductors

Conductors



- Good conductor of electricity.
- Offers almost **no resistance** to the **flow of current** of electrons.
 - Resistivity (ρ) of Copper (Cu) is $1.7 \times 10^{-8} \Omega\text{-m}$.
 - Resistance (R) = $\frac{\rho l}{A}$ $l = \text{length}$
 $A = \text{Cross-sectional area}$

Copper – Atomic structure

Bohr Model

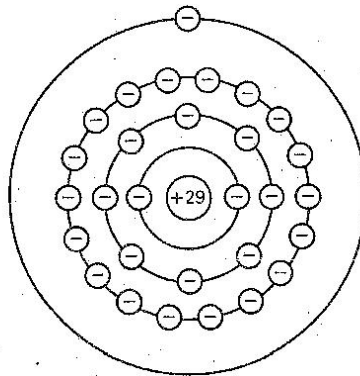
Copper (Cu)

No. of protons: 29

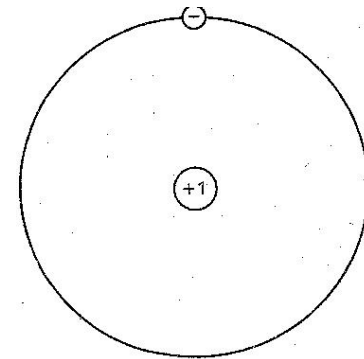
No. of electrons: 29

No. of neutrons: 35

Atomic number: 29



Copper (Cu) atom

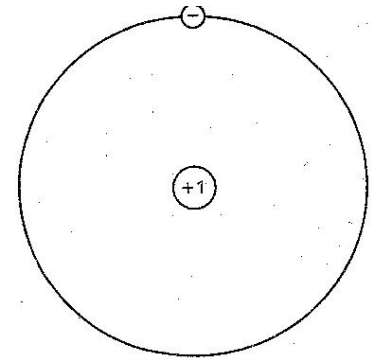


Copper core diagram

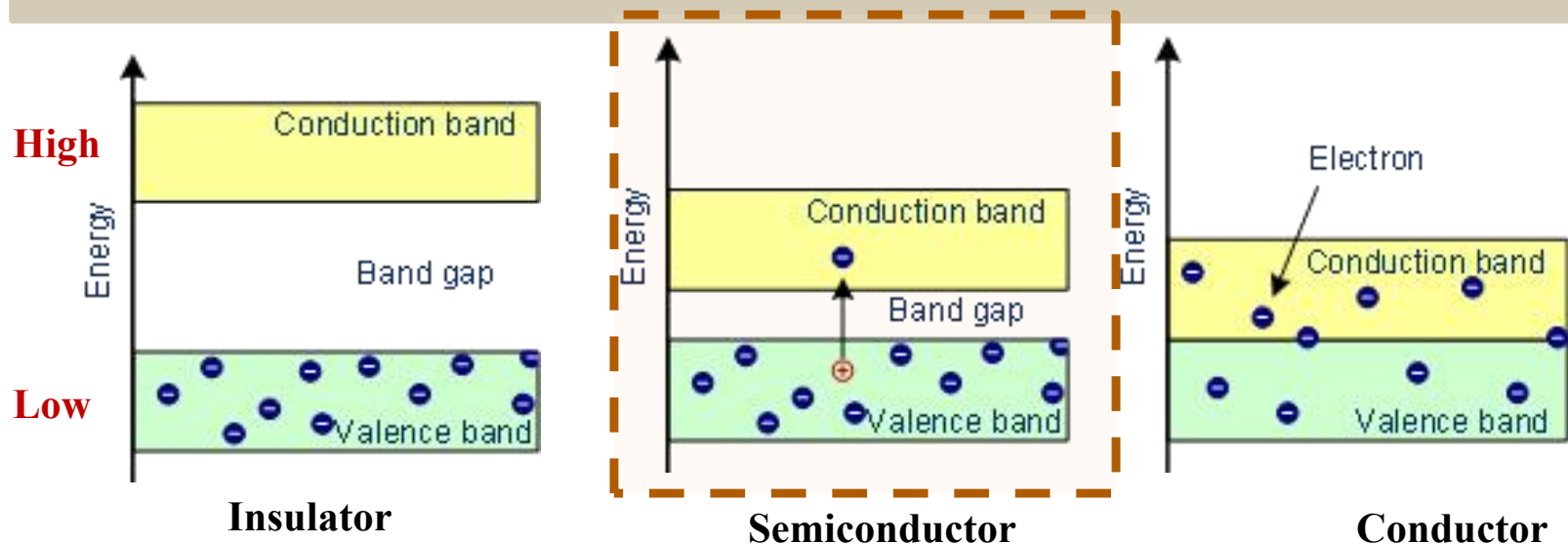
- In Electronics all that matter is in the **outer most orbit** which is called the **valence orbit**.
- Valence orbit **controls** the **electrical properties** of the atom.
- **Core** is defined as **nucleus** and **all the inner orbits**.
- **Core** of Copper is net +ve, because it has **29 protons** and **28 electrons**.
 - But, the **atom** is **electrically neutral** with **core + the valence electron**.

Why is Conductivity high for Cu?

- Since the attraction between the core and the single valence electron is very weak.
 - An outside force can easily dislodge this valence electron from the copper atom.
- Thus, **an valence electron from each atom of Cu becomes a free electron**, constituting **flow of current**.
 - **Valence electron of Cu** is also called as **free electron**.
 - **Copper** is a **good conductor** because of the presence of more free electrons.
- Other **good conductors** are:
 - **Silver (Ag), Gold (Au), Aluminum (Al)**



Conduction and Valence Bands



- Band structure shows the energy levels of electrons.
- **Electrons in the conduction band have higher energy compared to the electrons in the valence band.**
 - Electrons in conduction band have more kinetic energy to move around freely, because of reduced attractive force from the positively charged nucleus.
- **Band gap is the energy an electron needs to gain to move into the conduction band from the valence band.**

Insulators



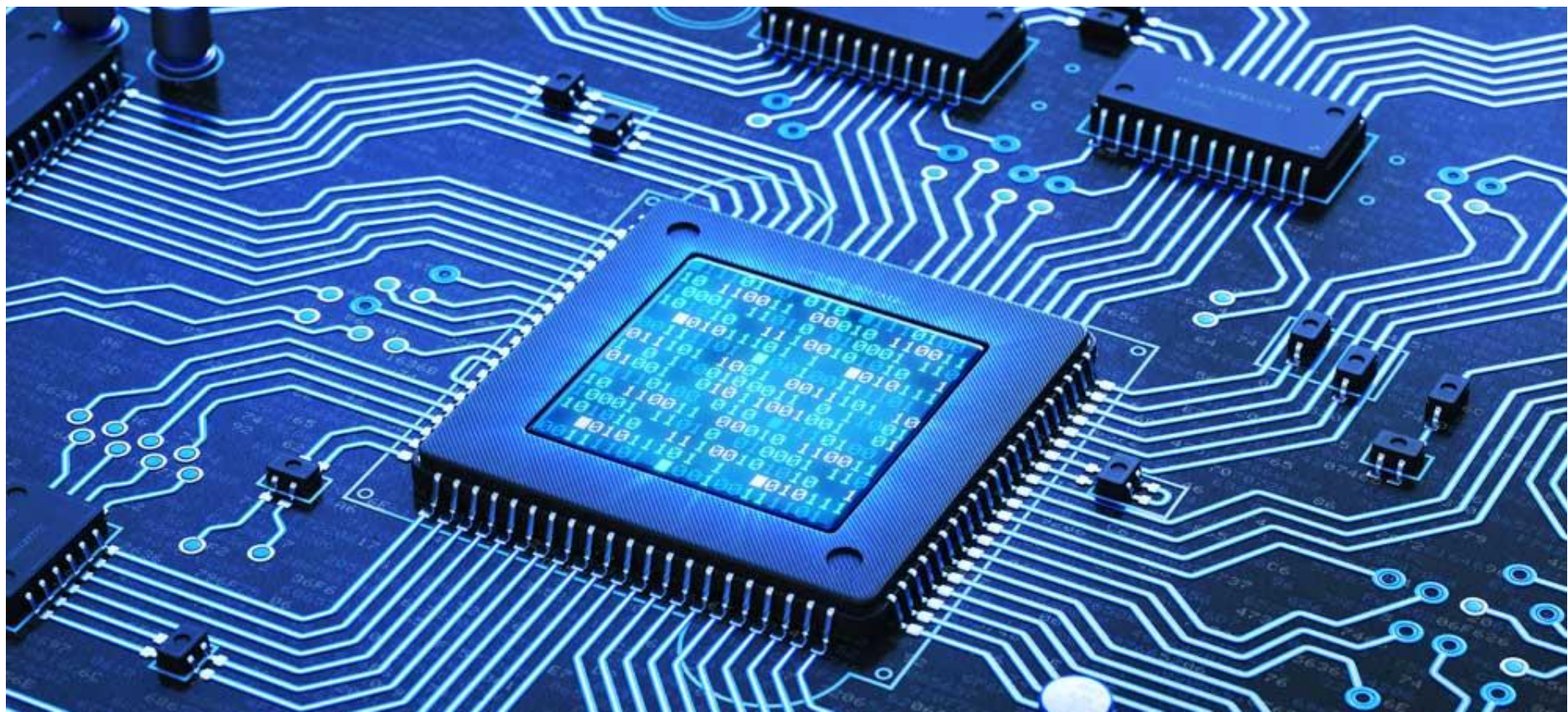
- It offers almost **infinite resistance** to the **flow of current** of electrons
 - **Glass resistivity (ρ)** - is $10^{12} \Omega\text{-m}$.
- Need much higher energy to dislodge an electron from the **valence band** to **conductance band**, due to large gap between them.

Resistivity Comparison (ρ)

Material	Resistivity at 25° C	Type of material
Silver	1.6×10^{-6}	Conductor
Silicon	55,000	Semiconductor
Germanium	55	Semiconductor
Mica	2×10^{12}	Insulator

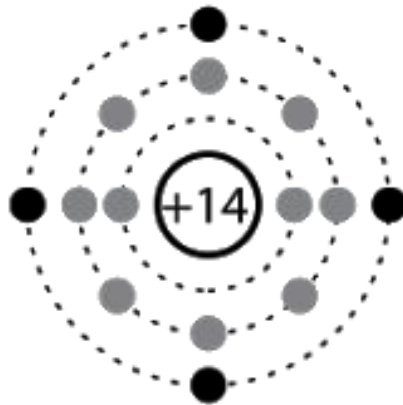
- **Semiconductors** have resistivity which is between the resistivities of conductors and insulators.
- **Electronic devices** are made of **semiconductors** due to this amazing property, which you will study further ...

Note: Resistivity (ρ) is given here in $\Omega \text{ cm}$

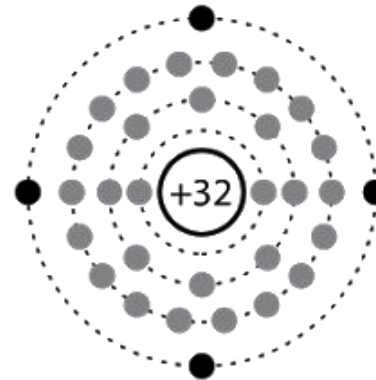


Intrinsic Semiconductors

Semiconductor Materials



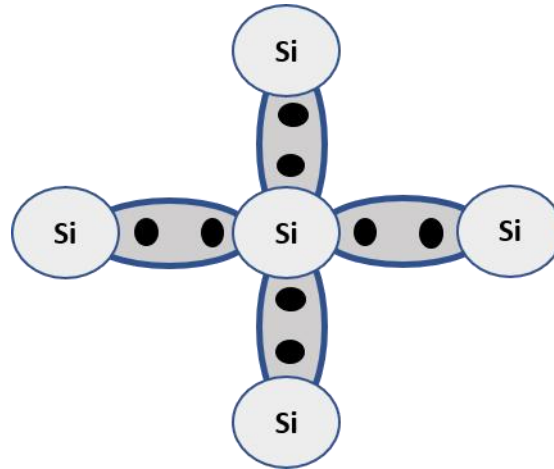
Silicon



Germanium

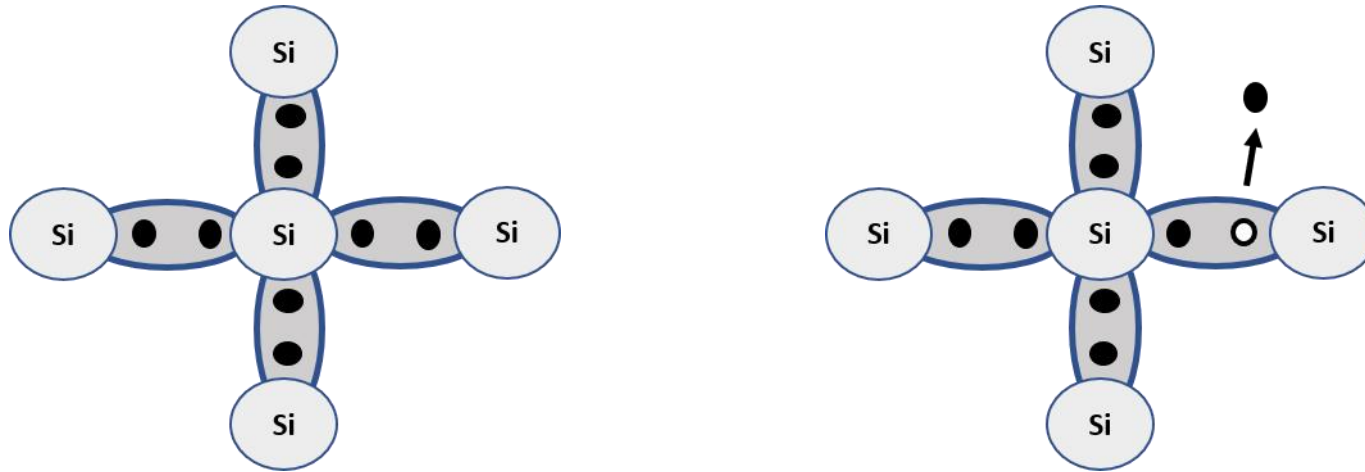
- **Atomic number of Silicon (Si) = 14**
 - Stable electron configuration of Si is: **2-8-4**
- **Atomic number of Germanium (Ge) = 32**
 - Stable electron configuration of Ge is: **2-8-18-4**

Intrinsic or Pure Semiconductor

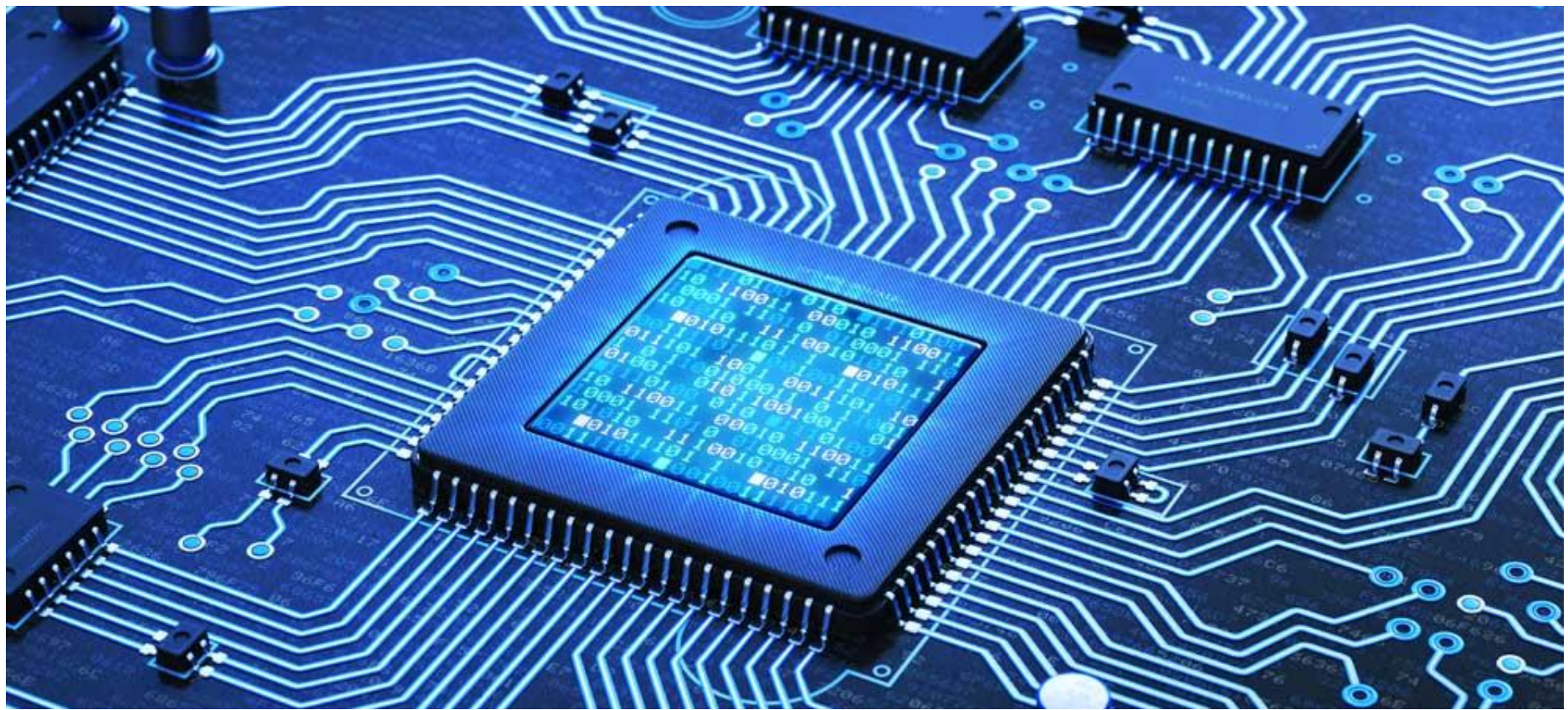


- An intrinsic semiconductor is an **undoped** or a **pure** semiconductor.
- **Undoped** means that the silicon material is not doped or mixed with any other materials or impurities.

Hole due to the Dislodging of an Electron

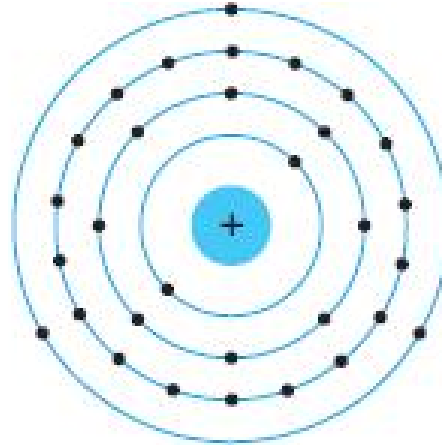


- In a pure silicon crystal, occasionally electrons from the valence band get dislodged due to heat or light.
- Then, the released electron gains enough energy to go into the conduction band, becoming a free electron.
- The departure of the electron creates a vacancy in the valence band called a **hole**.



Doping Materials

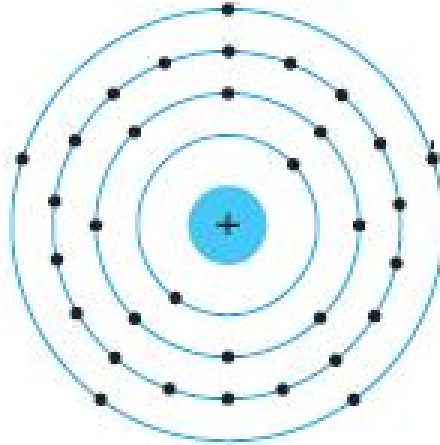
Trivalent Elements



Gallium

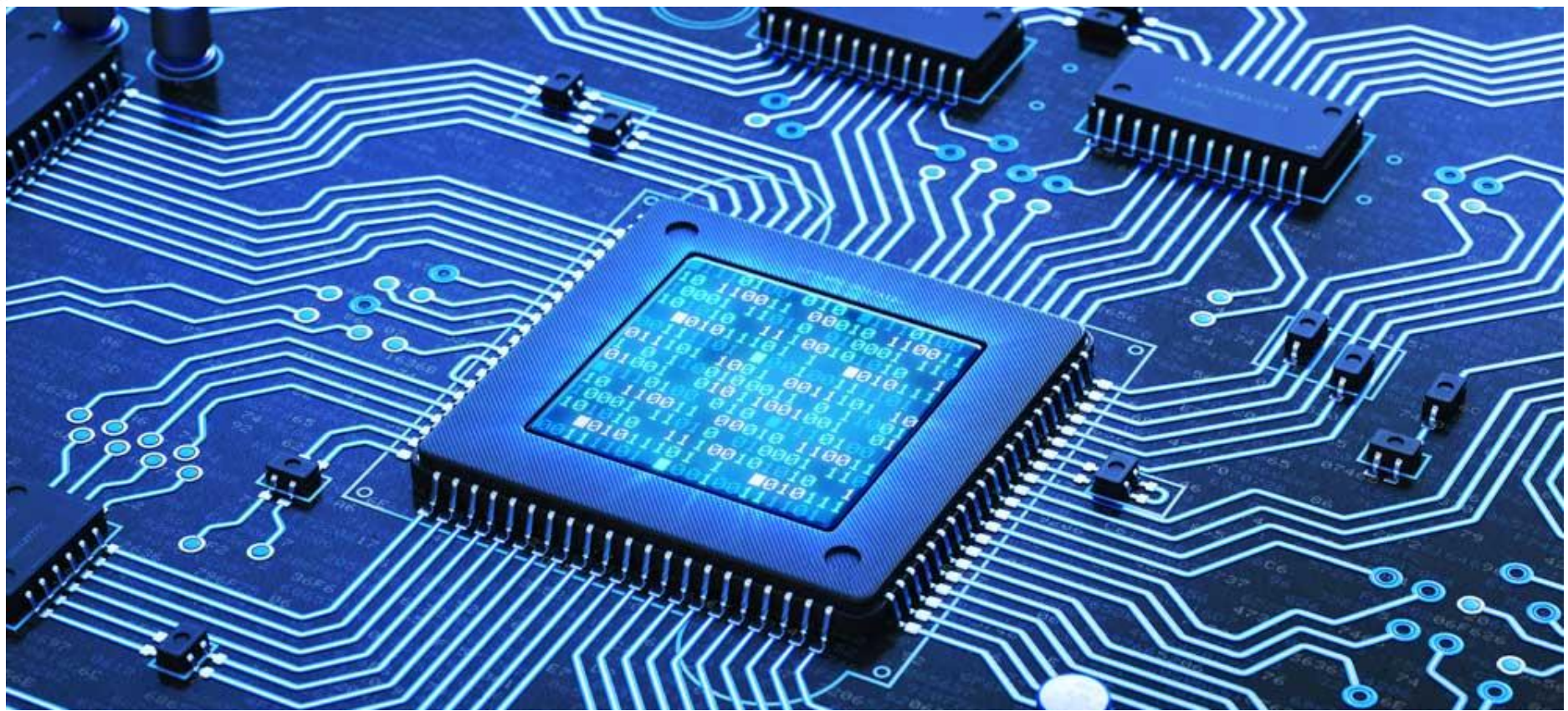
- **Atomic number of Gallium = 31 Trivalent**
 - Stable electron configuration of **Ga** is: **2-8-18-3**
 - Other **trivalent** elements are: Aluminium, Boron and Gallium

Pentavalent Elements



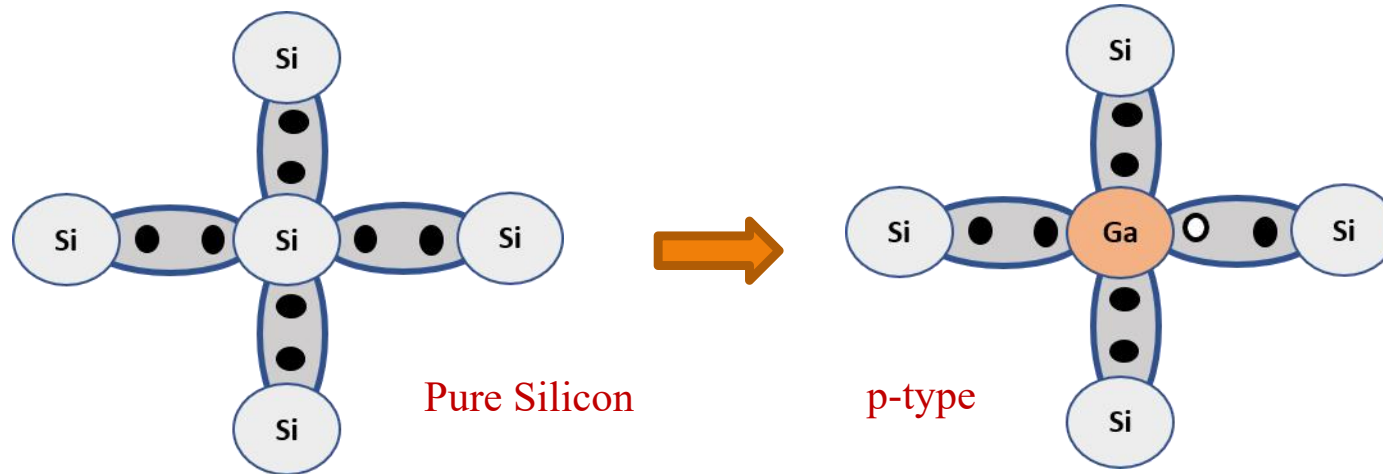
Arsenic

- **Atomic number of Arsenic = 33 Pentavalent**
 - Stable electron configuration of As is: **2-8-18-5**.
 - Other **pentavalent** elements are: Arsenic, Antimony and Phosphorus.



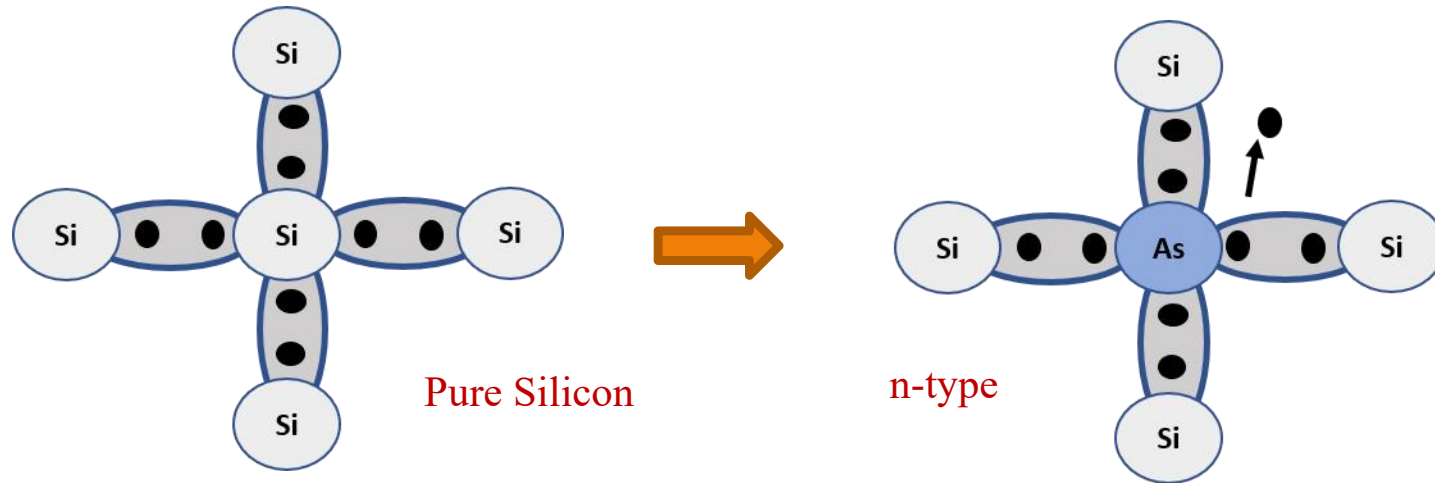
Doped Semiconductors

p-type Semiconductor



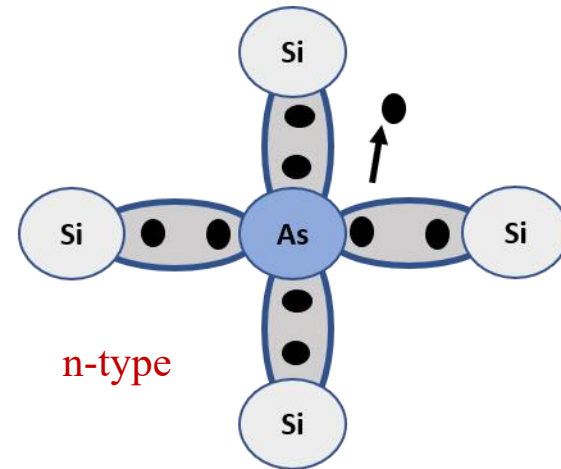
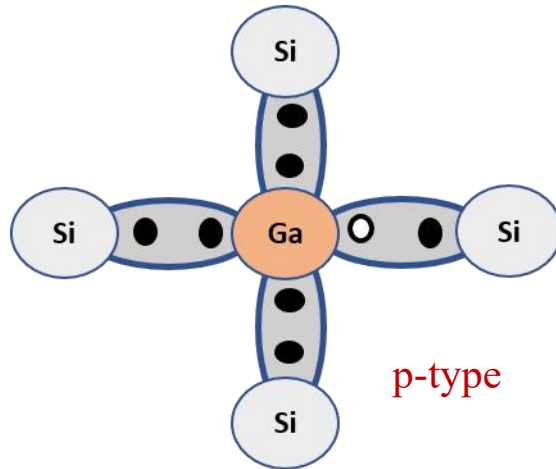
- **Doping** is the process of adding different materials (impurities) to a semiconductor materials (Si, Ge, etc.).
- When the Silicon is added with **trivalent** impurities (**Ga**, Gallium), each trivalent atom dislodges one silicon atom, thus adding a **hole**.
- Holes are nothing but absence of electrons, thus considered to be positively charged.
- So, **trivalent** elements are called as **p-type** materials.

n-type Semiconductor



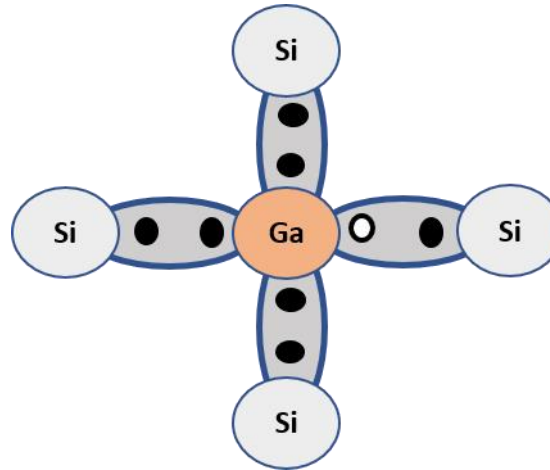
- When the Silicon is added with **pentavalent** impurities (**As**, Arsenic), each pentavalent atom dislodges one silicon atom, thus adding an **electron**.
- So, **pentavalent** elements are called as **n-type** materials.

Types of Doping



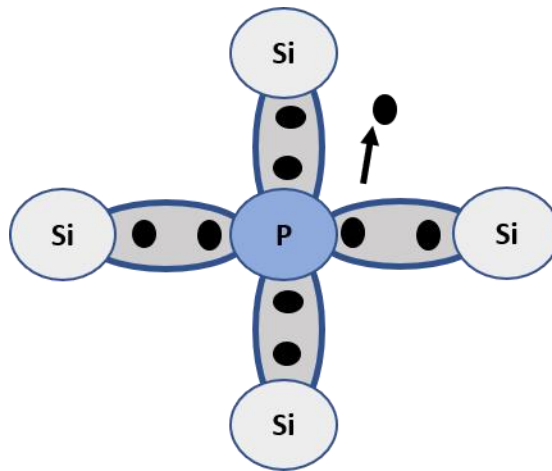
- Trivalent or Pentavalent elements are used to dope Semiconductor materials (Silicon or Germanium).
- Doping changes the electrical properties of semiconductor material, by adding either more free electrons or holes.
- **Pentavalent** elements are called **donor** impurities since they contribute one free electron for every atom added.
 - Whereas **trivalent** elements are called **acceptors** because it adds one hole per an atom of impurity.

p-type Material

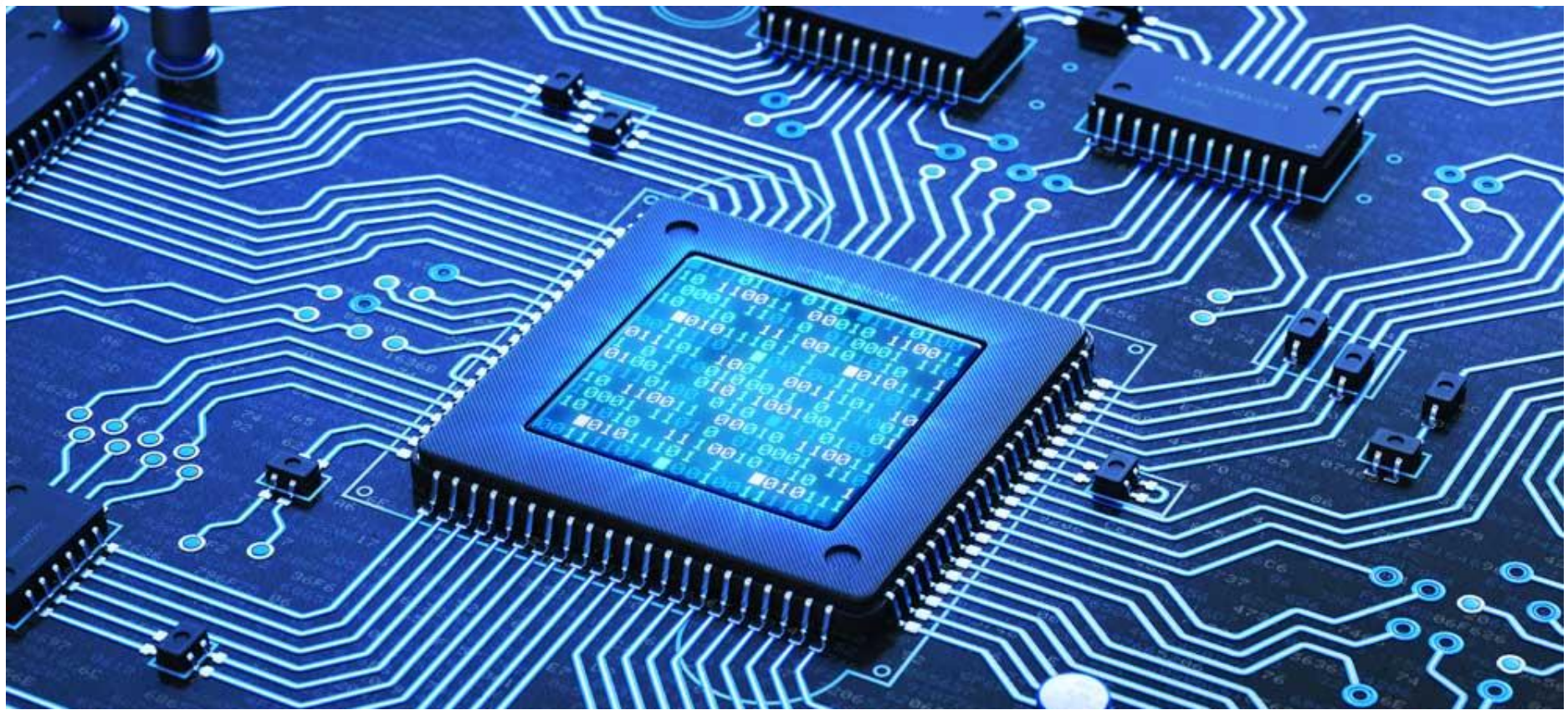


- In the **p-type** material **holes** are **majority carriers** and the **electrons** are **minority carriers**

n-type Material



- In the **n-type** material **electrons** are **majority** carriers and the **holes** are **minority** carriers.

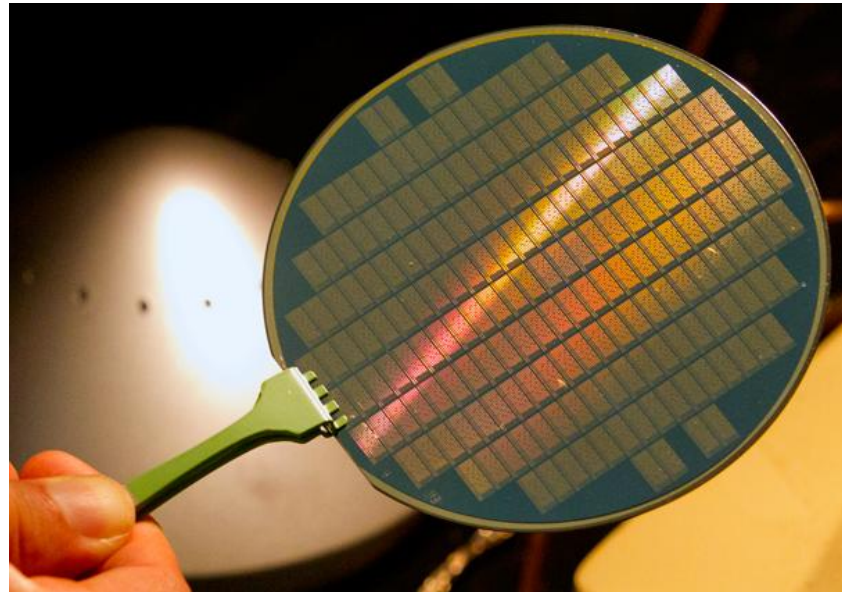


Silicon Wafer

Silicon Material to Wafer



Each individual squares are one independent Integrated Chip (IC) etched on to a thin **wafer** of **Silicon** material



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